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I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as first class mail in an envelope addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450:

By:

Date:

July 17, 2003

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant : Lars-Peter Heineck et al.
Applic. No. : 09/885,553 ✓
Filed : June 20, 2001
Title : MOS Transistor in a Single-Transistor Memory Cell Having a Locally Thickened Gate Oxide
Examiner : Johannes P. Mondt
Group Art Unit : 2826

R E S P O N S E

Hon. Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

S i r :

Responsive to the Office action dated April 17, 2003 kindly consider the following remarks:

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